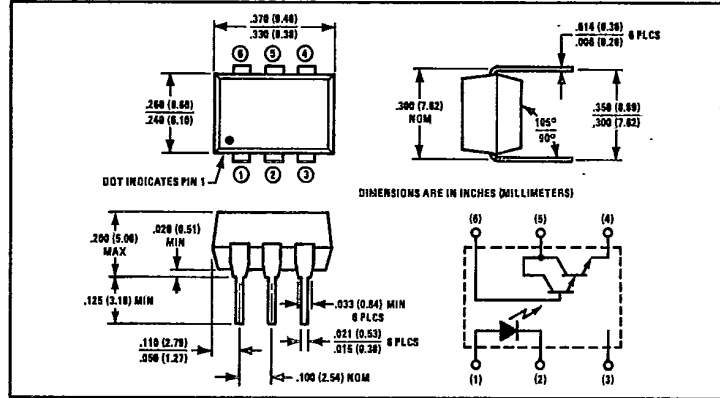
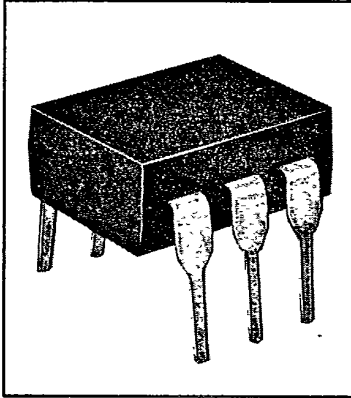


Optically Coupled Isolators

Types OPI3152, OPI3252



Features

- Photodarlington output
- High current transfer ratio
- 2500 or 1500 volt isolation ratings
- UL recognized File No. E58730

Description

The OPI3152 and OPI3252 are optically coupled isolators each consisting of a gallium arsenide infrared emitting diode and an NPN silicon photodarlington mounted in a standard plastic six pin dual-in-line package. Except for isolation voltage, the OPI3152 and OPI3252 are identical.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Input-to-Output Isolation Voltage — OPI3152 $\pm 1500 \text{ VDC}^{(1)}$
OPI3252 $\pm 2500 \text{ VDC}^{(1)}$

Storage Temperature Range -55°C to $+150^\circ\text{C}$

Operating Temperature Range -55°C to $+100^\circ\text{C}$

Lead Soldering Temperature (1/16 inch [1.6 mm] from case for 5 sec. with soldering iron)⁽²⁾ 260°C

Input Diode

Forward DC Current 60 mA

Peak Forward Current (1 μs pulse width, 330 pps) 3.0 A

Reverse DC Voltage 3.0 V

Power Dissipation 100 mW⁽³⁾

Output Transistor

Collector-Emitter Voltage 55 V

Collector-Base Voltage 55 V

Emitter-Collector Voltage 5.0 V

Power Dissipation 150 mW⁽⁴⁾

Notes:

- (1) Measured with input diode leads shorted together and output leads shorted together.
- (2) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
- (3) Derate linearly 1.33 mW/ $^\circ\text{C}$ above 25°C .
- (4) Derate linearly 2.0 mW/ $^\circ\text{C}$ above 25°C .

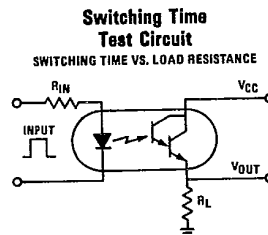
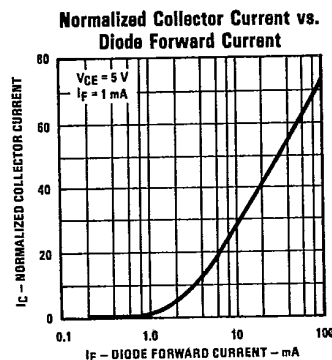
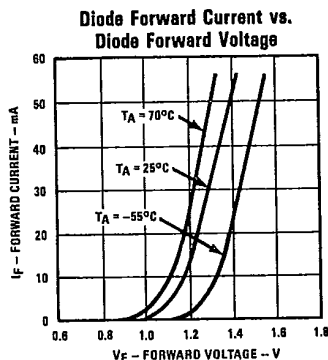
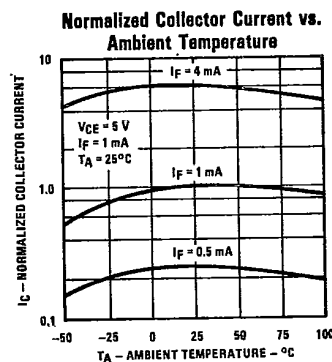
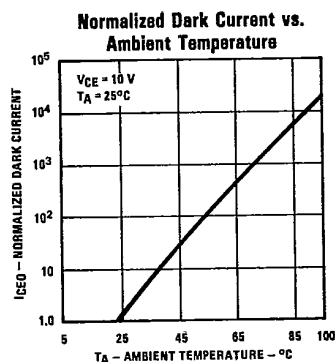
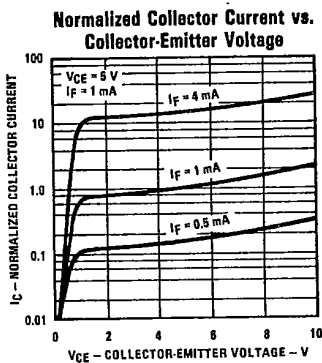
Types OPI3152, OPI3252

T-41-85

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Input Diode						
V_F	Forward Voltage			1.50	V	$I_F = 10.0\text{ mA}$
I_R	Reverse Current			100	μA	$V_R = 3.0\text{ V}$
Output Photodarlington						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	55			V	$I_C = 100\text{ }\mu\text{A}$, $I_B = 0$
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	65			V	$I_C = 100\text{ }\mu\text{A}$, $I_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5.0			V	$I_E = 100\text{ }\mu\text{A}$, $I_B = 0$
I_{CEO}	Collector-Emitter Dark Current			100	nA	$V_{CE} = 10.0\text{ V}$, $I_B = 0$
Coupled						
I_C/I_F	DC Current Transfer Ratio	300			%	$I_F = 10.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage			1.20	V	$I_F = 50\text{ mA}$, $I_C = 50\text{ mA}$, $I_B = 0$
t_r	Output Rise Time		3.0		μs	$V_{CC} = 10.0\text{ V}$, $I_C = 10.0\text{ mA}$, $R_L = 100\Omega$
t_f	Output Fall Time		25		μs	See Test Circuit

Typical Performance Curves



NOTE: Rise Time (t_r) is time required for collector current to increase from 10% to 90% of its final value. Fall Time (t_f) is time required for the collector current to decrease from 90% to 10% of its initial value.

TRW reserves the right to make changes at any time in order to improve design and to supply the best product possible.

Plastic color may vary.

Optoelectronics Division, TRW Electronic Components Group, 1215 W. Crosby Rd., Carrollton, TX 75006 (214) 323-2200, TLX 6716032 or 215649
© TRW Inc. 1985, 1982. TRW is the name and mark of TRW Inc.

Printed in U.S.A.

Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com